

Digital Transistor

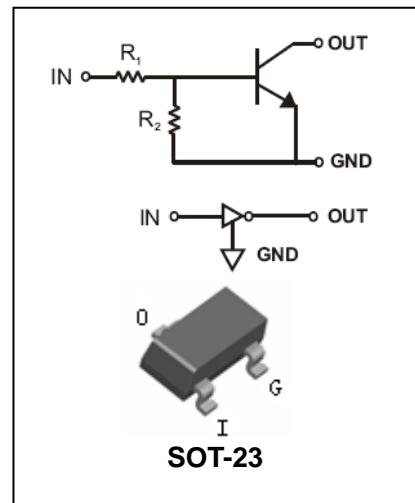
DTC($R_1 \neq R_2$ SERIES)CA

FEATURES

- Epitaxial planar die construction.
- Complementary PNP types available(DTA).
- Built-in biasing resistors, $R_1 \neq R_2$.
- Also available in lead free version.

APPLICATIONS

- The NPN style digital transistor.



MAXIMUM RATING @ $T_a=25^\circ\text{C}$ unless otherwise specified

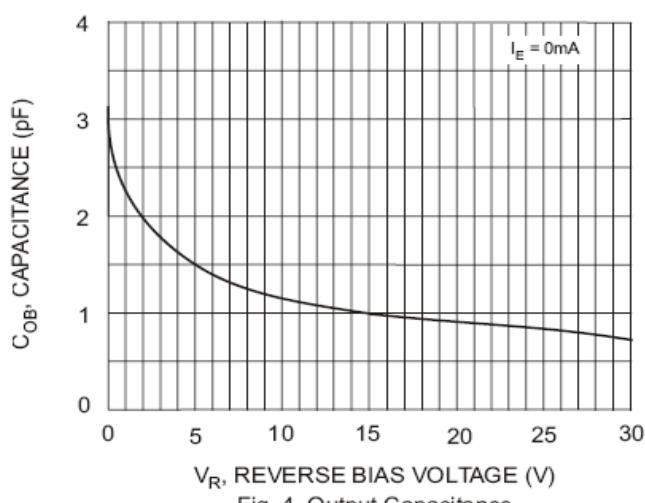
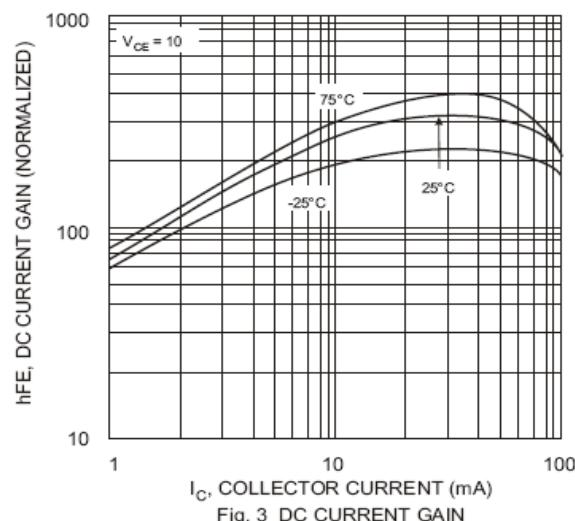
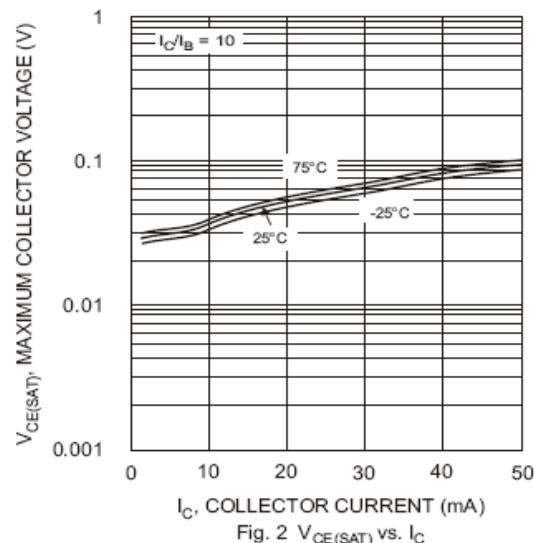
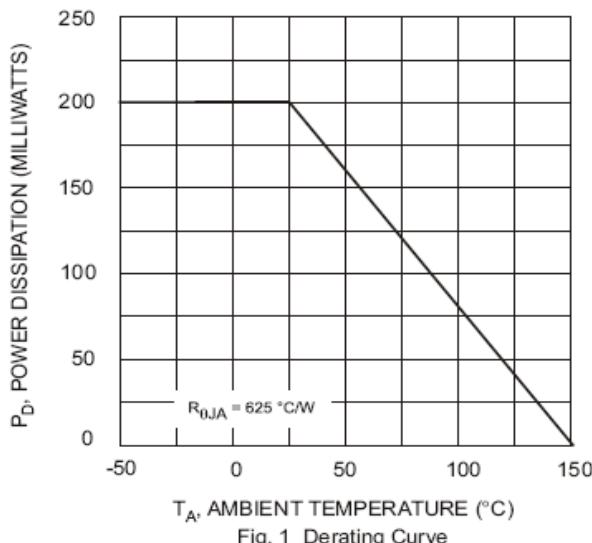
Symbol	Parameter	Value	Units
V_{CC}	Supply Voltage	50	V
V_{IN}	Input Voltage	DTC113ZCA DTC114WCA DTC114YCA DTC123JCA DTC123YCA DTC143XCA DTC143ZCA	-5 to +10 -10 to +30 -6 to +40 -5 to +12 -5 to +12 -7 to +20 -5 to +30
			V
I_O	Output Current	DTC113ZCA DTC114WCA DTC114YCA DTC123JCA DTC123YCA DTC143XCA DTC143ZCA	100 100 70 100 100 100 100
			mA
$I_C(\text{Max.})$	Output current	ALL	100
P_D	Power Dissipation		200
			mW

Symbol	Parameter	Value	Units
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient Air	625	°C/W
T_j, T_{stg}	Operating and Storage and Temperature Range	-55 to +150	°C

ELECTRICAL CHARACTERISTICS @ $T_a=25^\circ C$ unless otherwise specified

Parameter	Symbol	Test conditions	MIN	TYP	MAX	UNIT
Input Voltage	$V_{I(off)}$	$V_{CC}=5V, I_o=100\mu A$	0.3			V
			0.8			
			0.3			
			0.5	-	-	
			0.3			
			0.3			
			0.5			
Input Voltage	$V_{I(on)}$	$V_o=0.3V, I_o=20mA$			3.0	V
		$V_o=0.3V, I_o=2mA$			3.0	
		$V_o=0.3V, I_o=1mA$			1.4	
		$V_o=0.3V, I_o=5mA$	-	-	1.1	
		$V_o=0.3V, I_o=20mA$			3.0	
		$V_o=0.3V, I_o=20mA$			2.5	
		$V_o=0.3V, I_o=5mA$			1.3	
Output Voltage	$V_{O(on)}$	$I_o/I_i=5mA/0.25mA$			0.3	V
		$I_o/I_i=10mA/0.5mA$	-	0.1		
Input Current	I_i	$V_i=5V$			7.2	mA
					0.88	
					0.88	
			-	-	3.6	
					3.8	
					1.8	
					1.8	
Output Current	$I_{O(off)}$	$V_{CC}=50V, V_i=0V$	-	-	0.5	μA
DC Current Gain	G_i	$V_o=5V, I_o=10mA$	33			
			24			
			68			
			80	-	-	
			33			
			30			
			80			

Parameter	Symbol	Test conditions	MIN	TYP	MAX	UNIT
Input Resistor	$R_1(R_2)$		0.7	1(10)	1.3	
			7	10(4.7)	13	
			7	10(47)	13	
			1.54	2.2(47)	2.86	$\text{k}\Omega$
			1.54	2.2(10)	2.86	
			3.29	4.7(10)	6.11	
			3.29	4.7(47)	6.11	
Input Resistor (R_1) Tolerance	ΔR_1	-	-30		+30	%
Resistance Ratio Tolerance	$\Delta R_2/R_1$	-	-20		+20	%
Gain-Bandwidth Product	f_T	$V_{CE}=10\text{V}, I_E=5\text{mA}, f=100\text{MHz}$	-	250	-	MHz

TYPICAL CHARACTERISTICS @ $T_a=25^\circ\text{C}$ unless otherwise specified

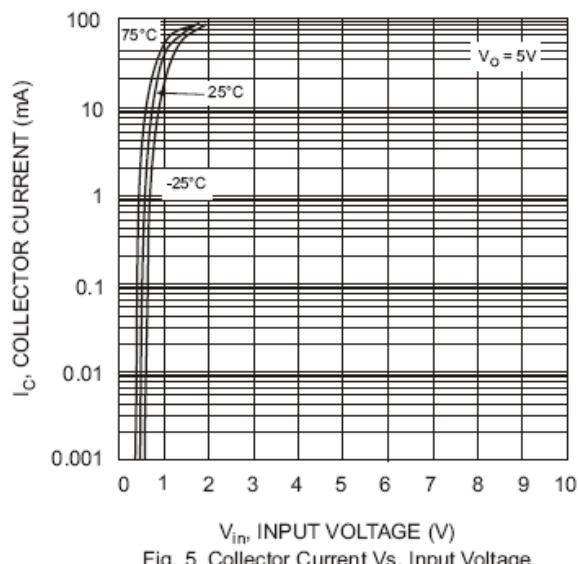


Fig. 5 Collector Current Vs. Input Voltage

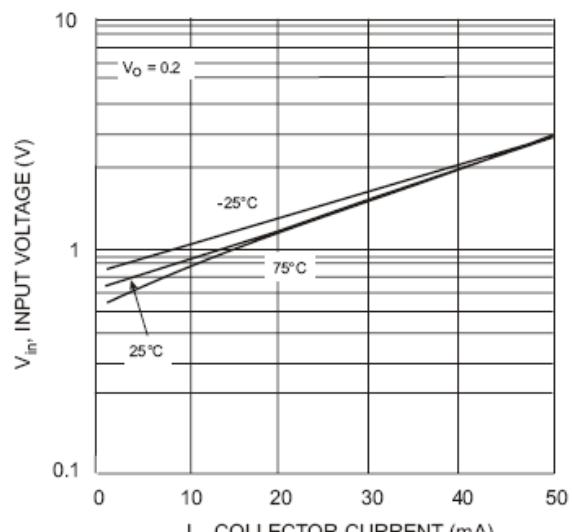


Fig. 6 Input Voltage vs. Collector Current

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